3.3V CMOS OCTAL BUFFER/DRIVER WITH 3-STATE OUTPUTS

IDT74ALVC244

FEATURES:

- 0.5 MICRON CMOS Technology
- Typical $t_{SK(o)}$ (Output Skew) < 250ps
- ESD > 2000V per MIL-STD-883, Method 3015; > 200V using machine model (C = 200pF, R = 0)
- V_{CC} = 3.3V ±0.3V, Normal Range
- V_{CC} = 2.7V to 3.6V, Extended Range
- V_{CC} = 2.5V ±0.2V
- CMOS power levels (0.4µW typ. static)
- Rail-to-Rail output swing for increased noise margin
- Available in SOIC, SSOP, QSOP, and TSSOP packages

Drive Features for ALVC244:

- High Output Drivers: ±24mA
- Suitable for heavy loads

APPLICATIONS:

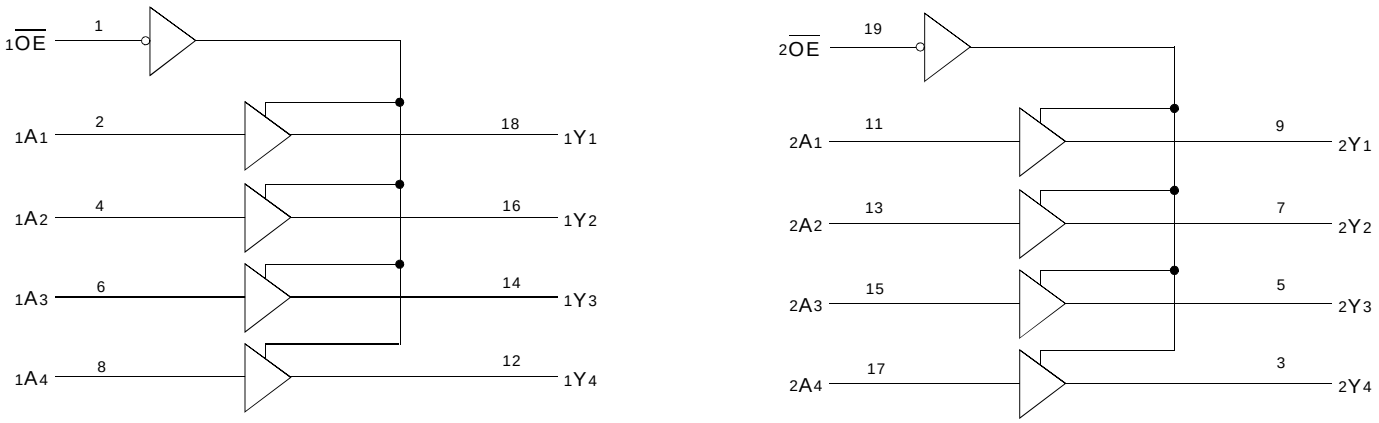
- 3.3V High Speed Systems
- 3.3V and lower voltage computing systems

DESCRIPTION:

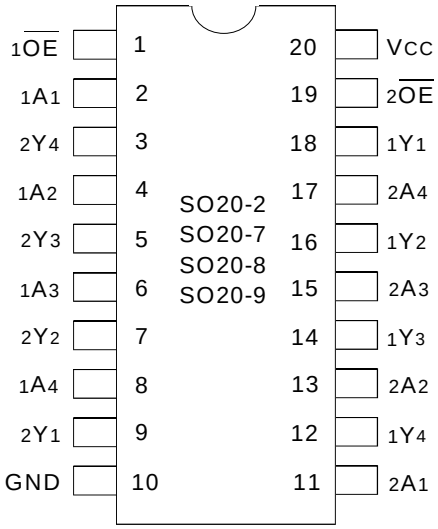
This octal buffer/driver is built using advanced dual metal CMOS technology. The ALVC244 is organized as two 4-bit line drivers with separate output-enable ($\overline{OE}$) inputs. When $\overline{OE}$ is low, the device passes data from the A inputs to the Y outputs. When $\overline{OE}$ is high, the outputs are in the high-impedance state.

The ALVC244 has been designed with a ±24mA output driver. This driver is capable of driving a moderate to heavy load while maintaining speed performance.

FUNCTIONAL BLOCK DIAGRAM



PIN CONFIGURATION



SSOP/ TVSOP/ TSSOP/ QSOP
TOP VIEW

ABSOLUTE MAXIMUM RATINGS (1)

Symbol	Description	Max.	Unit
V_{TERM}(2)	Terminal Voltage with Respect to GND	– 0.5 to +4.6	V
V_{TERM}(3)	Terminal Voltage with Respect to GND	–0.5 to V_{CC} +0.5	V
I_{OUT}	DC Output Current	– 50 to +50	mA
I_{IK}	Continuous Clamp Current, $V_I < 0$ or $V_I > V_{CC}$	±50	mA
I_{OK}	Continuous Clamp Current, $V_O < 0$	–50	mA
I_{CC} I_{SS}	Continuous Current through each V_{CC} or GND	±100	mA
T_{STG}	Storage Temperature	– 65 to +150	°C

ALVC Link

NOTES:
1. Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.
2. V_{CC} terminals.
3. All terminals except V_{CC}.

CAPACITANCE (T_A = +25°C, f = 1.0MHz)

Symbol	Parameter(1)	Conditions	Typ.	Max.	Unit
C_{IN}	Input Capacitance	V_{IN} = 0V	5	7	pF
C_{OUT}	Output Capacitance	V_{OUT} = 0V	7	9	pF
$C_{I/O}$	I/O Port Capacitance	V_{IN} = 0V	7	9	pF

ALVC Link

NOTE:
1. As applicable to the device type.

PIN DESCRIPTION

Pin Names	Description
x$\overline{OE}$	3-State Output Enable Inputs (Active LOW)
xAx	Data Inputs
xYx	3-State Outputs

FUNCTION TABLE (each buffer) (1)

Inputs		Outputs
x$\overline{OE}$	xAx	xYx
L	H	H
L	L	L
H	X	Z

NOTE:
1. H = HIGH Voltage Level
   L = LOW Voltage Level
   X = Don't Care
   Z = High-Impedance

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:
Operating Condition: T_A = –40°C to +85°C

Symbol	Parameter	Test Conditions		Min.	Typ.(1)	Max.	Unit
V_{IH}	Input HIGH Voltage Level	V_{CC} = 2.3V to 2.7V		1.7	—	—	V
		V_{CC} = 2.7V to 3.6V		2	—	—	
V_{IL}	Input LOW Voltage Level	V_{CC} = 2.3V to 2.7 V		—	—	0.7	V
		V_{CC} = 2.7V to 3.6V		—	—	0.8	
I_{IH}	Input HIGH Current	V_{CC} = 3.6V	V_I = V_{CC}	—	—	± 5	µA
I_{IL}	Input LOW Current	V_{CC} = 3.6V	V_I = GND	—	—	± 5	
I_{OZH}	High Impedance Output Current	V_{CC} = 3.6V	V_O = V_{CC}	—	—	± 10	µA
I_{OZL}	(3-State Output pins)		V_O = GND	—	—	± 10	µA
V_{IK}	Clamp Diode Voltage	V_{CC} = 2.3V, I_{IN} = –18mA		—	– 0.7	– 1.2	V
V_H	Input Hysteresis	V_{CC} = 3.3V		—	100	—	mV
I_{CCL} I_{CCH} I_{CCZ}	Quiescent Power Supply Current	V_{CC} = 3.6V V_{IN} = GND or V_{CC}		—	0.1	10	µA
ΔI_{CC}	Quiescent Power Supply Current Variation	One input at V_{CC} – 0.6V, other inputs at V_{CC} or GND		—	—	750	µA

ALVC Link

NOTE:
1. Typical values are at V_{CC} = 3.3V, +25°C ambient.

OUTPUT DRIVE CHARACTERISTICS

Symbol	Parameter	Test Conditions(1)		Min.	Max.	Unit
V_{OH}	Output HIGH Voltage	V_{CC} = 2.3V to 3.6V	I_{OH} = – 0.1mA	V_{CC} – 0.2	—	V
		V_{CC} = 2.3V	I_{OH} = – 6mA	2	—	
		V_{CC} = 2.3V	I_{OH} = – 12mA	1.7	—	
		V_{CC} = 2.7V		2.2	—	
		V_{CC} = 3.0V		2.4	—	
		V_{CC} = 3.0V	I_{OH} = – 24mA	2	—	
V_{OL}	Output LOW Voltage	V_{CC} = 2.3V to 3.6V	I_{OL} = 0.1mA	—	0.2	V
		V_{CC} = 2.3V	I_{OL} = 6mA	—	0.4	
			I_{OL} = 12mA	—	0.7	
		V_{CC} = 2.7V	I_{OL} = 12mA	—	0.4	
		V_{CC} = 3.0V	I_{OL} = 24mA	—	0.55	

ALVC Link

NOTE:
1. V_{IH} and V_{IL} must be within the min. or max. range shown in the DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE table for the appropriate V_{CC} range. T_A = – 40°C to + 85°C.

OPERATING CHARACTERISTICS, T_A = 25°C

Symbol	Parameter	Test Conditions	Vcc = 2.5V ± 0.2V Typical	Vcc = 3.3V ± 0.3V Typical	Unit
C_{PD}	Power Dissipation Capacitance Outputs enabled	C_L = 0pF, f = 10Mhz	22	28	pF
C_{PD}	Power Dissipation Capacitance Outputs disabled		1.5	4	pF

SWITCHING CHARACTERISTICS (1)

Symbol	Parameter	Vcc = 2.5V ± 0.2V Min.	Vcc = 2.5V ± 0.2V Max.	Vcc = 2.7V Min.	Vcc = 2.7V Max.	Vcc = 3.3V ± 0.3V Min.	Vcc = 3.3V ± 0.3V Max.	Unit
t_{PLH} t_{PHL}	Propagation Delay xAx to xYx	1	3.1	—	3.1	1.1	2.8	ns
t_{PZH} t_{PZL}	Output Enable Time x$\overline{OE}$ to xYx	1.5	5.4	—	5.3	1.5	4.5	ns
t_{PHZ} t_{PLZ}	Output Disable Time x$\overline{OE}$ to xYx	1	4.1	—	4.4	1.7	4.2	ns
$t_{SK}(o)$	Output Skew(2)	—	—	—	—	—	500	ps

NOTES:
1. See test circuits and waveforms. T_A = – 40°C to + 85°C.
2. Skew between any two outputs of the same package and switching in the same direction.

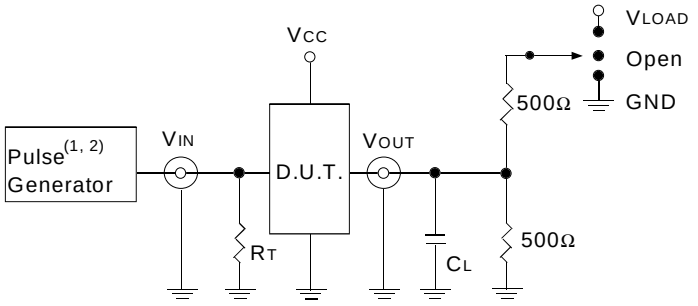
TEST CIRCUITS AND WAVEFORMS

TEST CONDITIONS

Symbol	$V_{CC}^{(1)}$= 3.3V ±0.3V	$V_{CC}^{(1)}$ = 2.7V	$V_{CC}^{(2)}$= 2.5V ±0.2V	Unit
V_{LOAD}	6	6	2 x Vcc	V
V_{IH}	2.7	2.7	Vcc	V
V_T	1.5	1.5	Vcc / 2	V
V_{LZ}	300	300	150	mV
V_{HZ}	300	300	150	mV
C_L	50	50	30	pF

ALVC Link

TEST CIRCUITS FOR ALL OUTPUTS



ALVC Link

DEFINITIONS:

C_L = Load capacitance: includes jig and probe capacitance.
R_T = Termination resistance: should be equal to Z_{OUT} of the Pulse Generator.

NOTES:

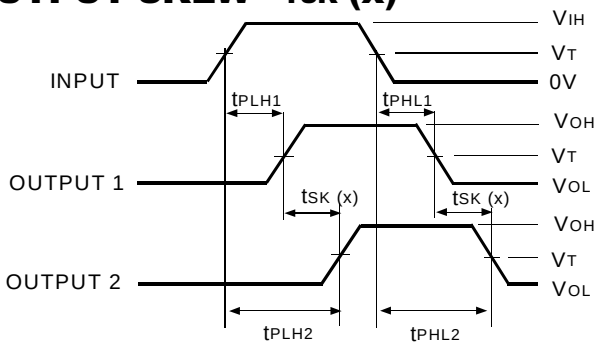
1. Pulse Generator for All Pulses: Rate ≤ 10MHz; t_F ≤ 2.5ns; t_R ≤ 2.5ns.
2. Pulse Generator for All Pulses: Rate ≤ 10MHz; t_F ≤ 2ns; t_R ≤ 2ns.

SWITCH POSITION

Test	Switch
Open Drain Disable Low Enable Low	V_{LOAD}
Disable High Enable High	GND
All Other tests	Open

ALVC Link

OUTPUT SKEW - t_{SK} (x)



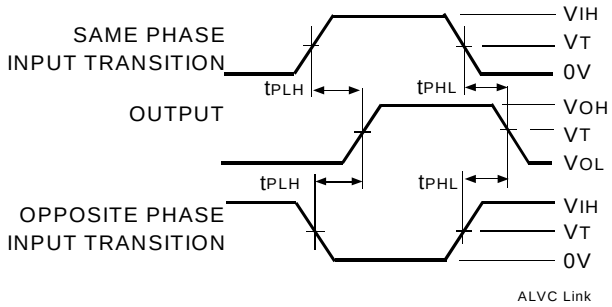
$t_{SK(x)} = |t_{PLH2} - t_{PLH1}|$ or $|t_{PHL2} - t_{PHL1}|$

ALVC Link

NOTES:

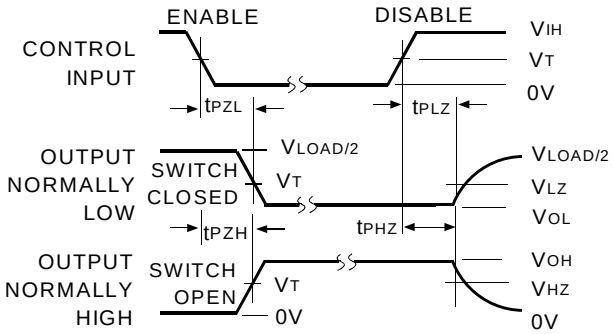
1. For t_{SK}(o) OUTPUT1 and OUTPUT2 are any two outputs.
2. For t_{SK}(b) OUTPUT1 and OUTPUT2 are in the same bank.

PROPAGATION DELAY



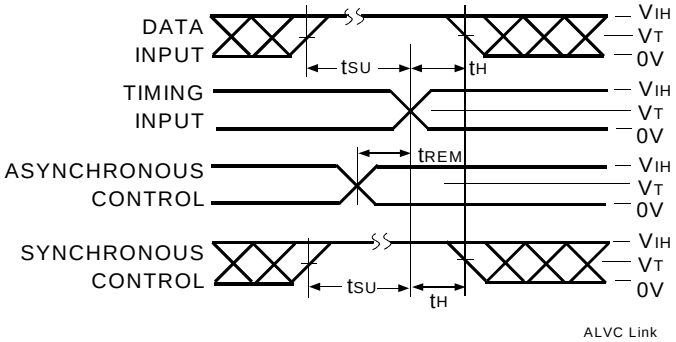
ALVC Link

ENABLE AND DISABLE TIMES



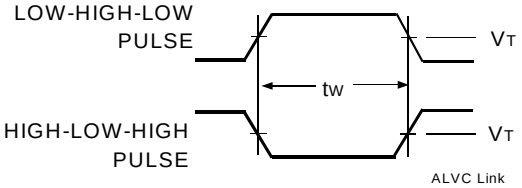
ALVC Link

SET-UP, HOLD, AND RELEASE TIMES



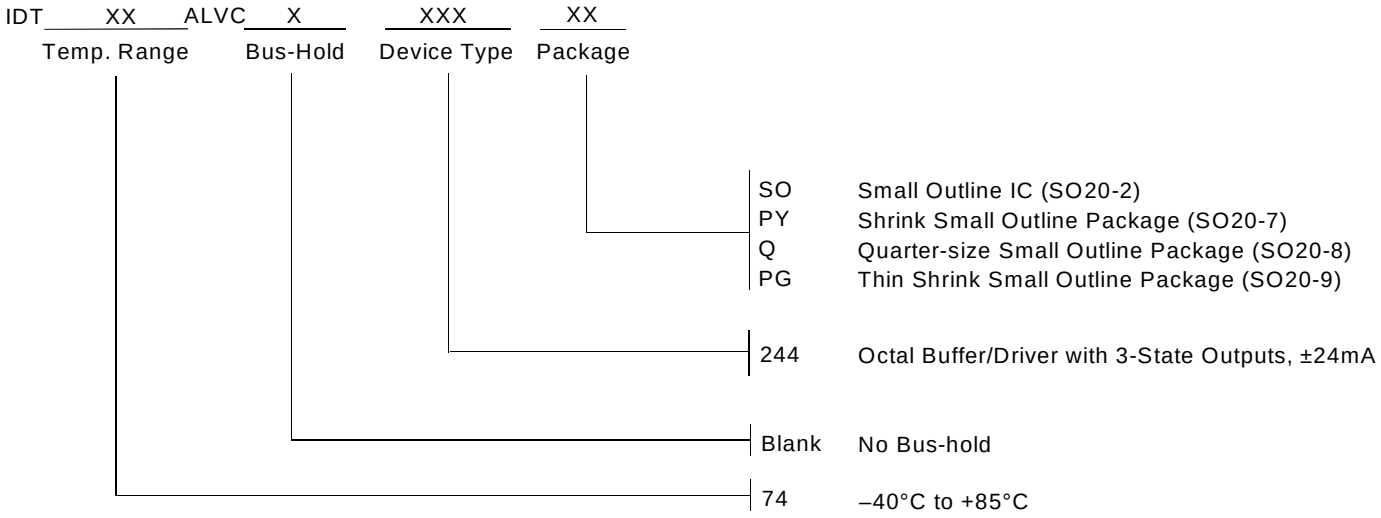
ALVC Link

PULSE WIDTH



ALVC Link

ORDERING INFORMATION



CORPORATE HEADQUARTERS
2975 Stender Way
Santa Clara, CA 95054

for SALES:
800-345-7015 or 408-727-6116
fax: 408-492-8674
www.idt.com*

**To search for sales office near you, please click the sales button found on our home page or dial the 800# above and press 2.*